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December 2009

# FJN3303F High Voltage Fast-Switching NPN Power Transistor

#### **Features**

- · High Voltage Capability
- · High Switching Speed
- Suitable for Electronic Ballast and Charger
- Green packaging



# **Absolute Maximum Ratings** $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	700	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	1.5	A
I <sub>CP</sub>	Collector Current (Pulse) *	3	A
Ι <sub>Β</sub>	Base Current (DC)	0.75	A
I <sub>BP</sub>	Base Current (Pulse) *	1.5	A
$T_J$	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature range	-65 to +150	°C

<sup>\*</sup> Pulse Test: Pulse Width = 5ms, Duty Cycle ≤ 10%

## **Thermal Characteristics** $T_A = 25$ °C unless otherwise noted

Symbol	Parameter		Value	Units	
P <sub>D</sub>	Total Device Dissipation	$T_C = 25^{\circ}C$ $T_A = 25^{\circ}C$	1.1 650	W mW	
$R_{\theta JC}$	Thermal Resistance Junction-Case		48	°C/W	
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		190	°C/W	

## **Ordering Information**

Part Number	Marking Info.	Package	Packing Method	Remarks
FJN3303FBU	J3303F	TO-92 (Straight)	BULK	Green EMC
FJN3303FTA	J3303F	TO-92 (Form)	AMMO	Green EMC

# **Electrical Characteristics** $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 500 \mu A, I_E = 0$	700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	400			٧
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	9			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			10	μΑ
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	$V_{CE} = 2V, I_{C} = 0.5A$ $V_{CE} = 2V, I_{C} = 1.0A$	14 5		23	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$\begin{aligned} & I_{C} = 0.5A, \ I_{B} = 0.1A \\ & I_{C} = 1.0A, \ I_{B} = 0.25A \\ & I_{C} = 1.5A, \ I_{B} = 0.5A \end{aligned}$			0.5 1.0 3.0	<b>&gt;</b> >
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 0.5A, I <sub>B</sub> = 0.1A I <sub>C</sub> = 1.0A, I <sub>B</sub> = 0.25A			1.0 1.2	V V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.1A$	4			MHz
t <sub>ON</sub>	Turn On Time	$V_{CC} = 125V, I_{C} = 1A$			1.1	μS
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = -0.2A$			4.0	μS
t <sub>F</sub>	Fall Time	$R_L = 125\Omega$			0.7	μS

# **Typical Performance Characteristics**

Figure 1. Static Characteristic

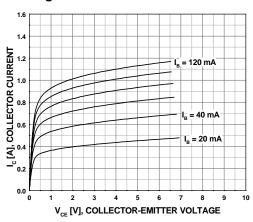


Figure 2. DC Current Gain

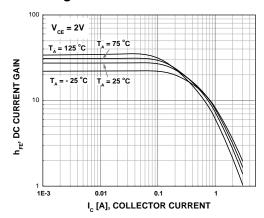


Figure 3. Collector-Emitter Saturation Voltage

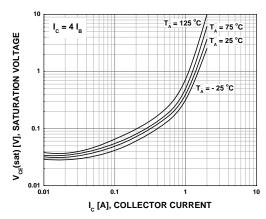


Figure 4. Base-Emitter Saturation Voltage

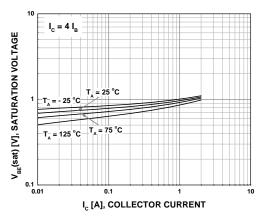


Figure 5. Resistive Load Switching Time

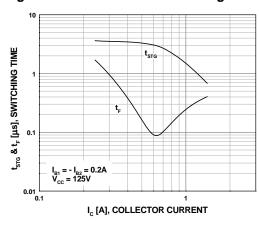
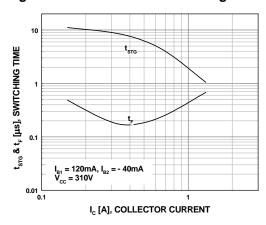


Figure 6. Resistive Load Switching Time



# **Typical Performance Characteristics** (Continued)

Figure 7. Forward Biased Safe Operating Area

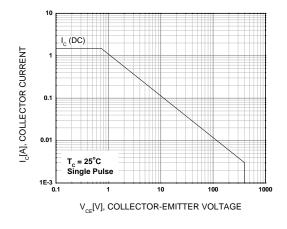
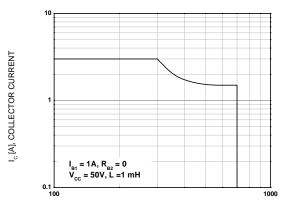
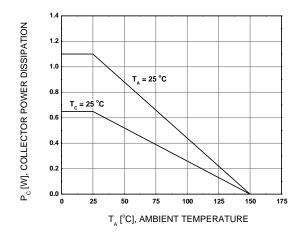


Figure 8. Reverse Biased Safe Operating Area

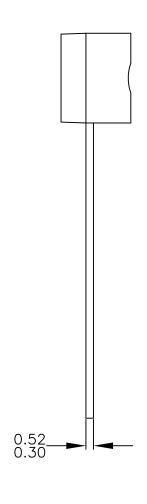


 $V_{\rm CE}$  [V], COLLECTOR-EMITTER VOLTAGE

Figure 9. Power Derating



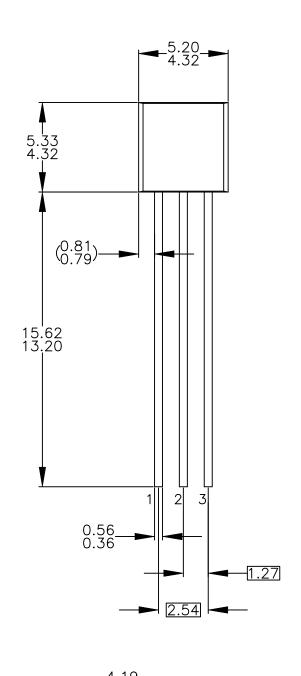






#### NOTES: UNLESS OTHERWISE SPECIFIED

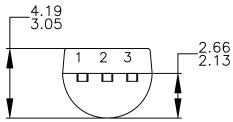
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  ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M-2009.
  DRAWING FILENAME: MKT-ZAO3FREV3.
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- B. C. D. E.





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